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## Expression of concern: A hysteresis-free perovskite transistor with exceptional stability through molecular cross-linking and amine-based surface passivation

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Expression of concern for 'A hysteresis-free perovskite transistor with exceptional stability through molecular cross-linking and amine-based surface passivation' by Hyeong Pil Kim *et al.*, *Nanoscale*, 2020, **12**, 7641–7650, <https://doi.org/10.1039/C9NR10745B>.

Nanoscale is publishing this expression of concern in order to alert readers that concerns have been raised regarding the integrity of the XRD data in Fig. 4, which the authors have said has been performed by a third party. We have asked the relevant affiliated institutions to investigate this matter fully. An expression of concern will continue to be associated with the article until we receive conclusive evidence regarding the reliability of the reported data.

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